

L Number	Hits	Search Text	DB	Time stamp
1	1	("6287899").PN.	USPAT	2004/04/01 11:24
2	394	contact adj (hole? via?) with (dimension? size?)	USPAT	2004/04/01 11:33
3	23	(contact adj (hole? via?) with (dimension? size?)) same (nitride silicon adj nitride)	USPAT	2004/04/01 11:25
4	0	(contact adj (hole? via?) with (dimension? size?)) with mm	USPAT	2004/04/01 11:32
5	22	contact adj (hole? via?) with (mm)	USPAT	2004/04/01 11:43
6	367	contact adj (hole? via?) same (diameter width) same (depth deep)	USPAT	2004/04/01 11:44
7	10	(contact adj (hole? via?) same (diameter width) same (depth deep)) and (thin adj film adj transistor TFT?)	USPAT	2004/04/01 12:30
8	485	(dielectric insulating) with silicon adj nitride same temperature?	USPAT	2004/04/01 11:55
9	0	(dielectric insulating) with silicon adj nitride same temperature? with minute?	USPAT	2004/04/01 11:56
10	37	silicon adj nitride same temperature? with minute?	USPAT	2004/04/01 12:44
11	3339	silicon adj nitride same temperature?	USPAT	2004/04/01 12:29
12	100	(silicon adj nitride same temperature?) and (thin adj film adj transistor TFT?)	USPAT	2004/04/01 12:46
13	100	((silicon adj nitride same temperature?) and (thin adj film adj transistor TFT?)) not (silicon adj nitride same temperature? with minute?)	USPAT	2004/04/01 12:31
14	128	silicon adj nitride same degree? with minute?	USPAT	2004/04/01 12:45
15	2	(silicon adj nitride same degree? with minute?) and (thin adj film adj transistor TFT?)	USPAT	2004/04/01 12:46